



### DMT10H032LDV

DUAL 100V N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8

## **Product Summary**

BV <sub>DSS</sub>	Rds(on) Max	I <sub>D</sub> Max Tc = +25°C			
4001/	$36m\Omega @ V_{GS} = 10V$	18A			
100V	50mΩ @ V <sub>GS</sub> = 4.5V	16A			

## Description

This new generation MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>), yet maintain superior switching performance, making it ideal for high efficiency power management applications.

## Applications

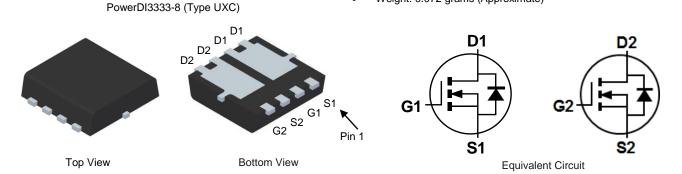
- Power Management Functions
- Analog Switch

### Features

- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

## **Mechanical Data**

- Case: PowerDI<sup>®</sup>3333-8
- Case Material: Molded Plastic, "Green" Molding Compound.
  UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.072 grams (Approximate)



## Ordering Information (Note 4)

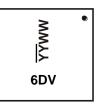
Part Number	Case	Packaging
DMT10H032LDV-7	PowerDI3333-8 (Type UXC)	2,000/Tape & Reel
DMT10H032LDV-13	PowerDI3333-8 (Type UXC)	3,000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



 $\begin{array}{l} \underline{6DV} = \mbox{Product Type Marking Code} \\ \hline \underline{YY}WW = \mbox{Date Code Marking} \\ \hline \underline{YY} = \mbox{Last Two Digits of Year (ex: 19 for 2019)} \\ \hline WW = \mbox{Week Code (01 to 53)} \end{array}$ 



### Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			VDSS	100	V
Gate-Source Voltage			V <sub>GSS</sub>	±20	V
Continuous Drain Current, V <sub>GS</sub> = 10V (Note 7)	Steady State	Tc = +25°C Tc = +70°C	ID	18 15	А
Maximum Body Diode Forward Current (Note 7)			ls	18	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			Ідм	75	A
Pulsed Drain Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)			lsм	75	A
Avalanche Current (L = 0.3mH) (Note 8)			las	13	А
Avalanche Energy (L = 0.3mH) (Note 8)			E <sub>AS</sub>	25.3	mJ

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		PD	1	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	RθJA	130	°C/W
Total Power Dissipation (Note 6)		PD	2.4	W
Thermal Resistance, Junction to Ambient (Note 6) Steady State		RθJA	51	°C/W
Thermal Resistance, Junction to Case (Note 7)	Rejc	6.6	C/W	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	100		—	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current TJ = +25°C	IDSS	_	_	1	μA	$V_{DS} = 80V, V_{GS} = 0V$	
Gate-Source Leakage		_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	Vgs(th)	1.3		2.5	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	Deserve	—	24	36	mΩ	$V_{GS} = 10V, I_D = 10A$	
	R <sub>DS(ON)</sub>	_	34	50	11152	Vgs = 4.5V, Ip = 5A	
Diode Forward Voltage	Vsd	_	0.8	1	V	$V_{GS} = 0V$ , $I_S = 6A$	
DYNAMIC CHARACTERISTICS (Note 10)	DYNAMIC CHARACTERISTICS (Note 10)						
Input Capacitance	Ciss	—	683	—	pF		
Output Capacitance	Coss	—	165		pF	Vps = 50V, Vgs = 0V, f = 1MHz	
Reverse Transfer Capacitance	Crss	—	6.9		pF	ברוויוו = וך	
Gate Resistance	Rg	—	1.2	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	_	6.3	_	nC		
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	_	11.9	_	nC		
Gate-Source Charge	Qgs	_	2.0		nC	$V_{DS} = 50V, I_D = 6A$	
Gate-Drain Charge	Qgd	_	3.1		nC		
Turn-On Delay Time	tD(ON)	_	4.1		ns		
Turn-On Rise Time	tR	_	4.5		ns	$V_{DS} = 50V, R_{L} = 5.85\Omega$	
Turn-Off Delay Time	tD(OFF)	_	12.5	—	ns	$V_{GS} = 10V, R_{GEN} = 3\Omega$	
Turn-Off Fall Time	tF	_	9.3		ns	1	
Reverse Recovery Time	trr	_	31.5		ns		
Reverse Recovery Charge	Qrr	_	94.6	_	nC	IF = 6A, di/dt = 500A/µs	

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

Bevice mounted on FR-4 substrate PC board, 202 copper, with 1inch square copper plate.
 Thermal resistance from junction to soldering point (on the exposed drain pad).

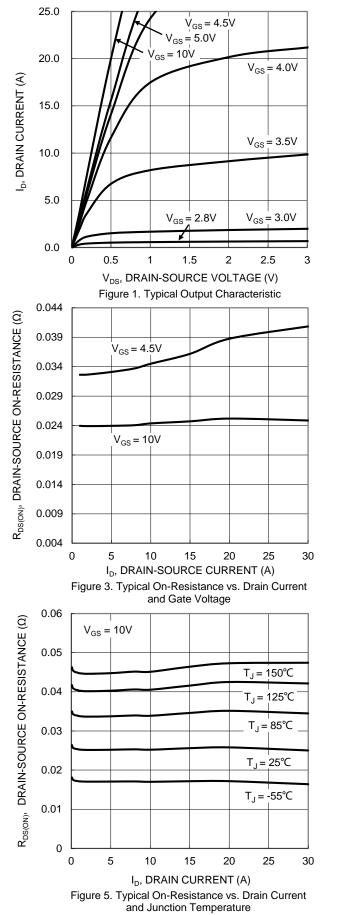
8. I<sub>AS</sub> and  $E_{AS}$  ratings are based on low frequency and duty cycles to keep  $T_J = +25^{\circ}C$ .

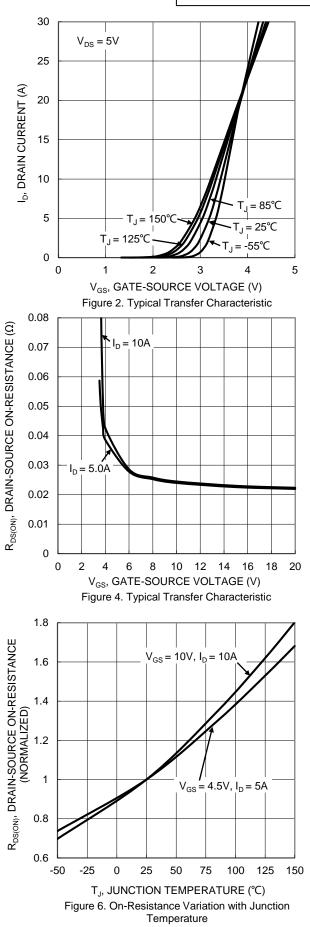
9. Short duration pulse test used to minimize self-heating effect.

10. Guaranteed by design. Not subject to product testing.



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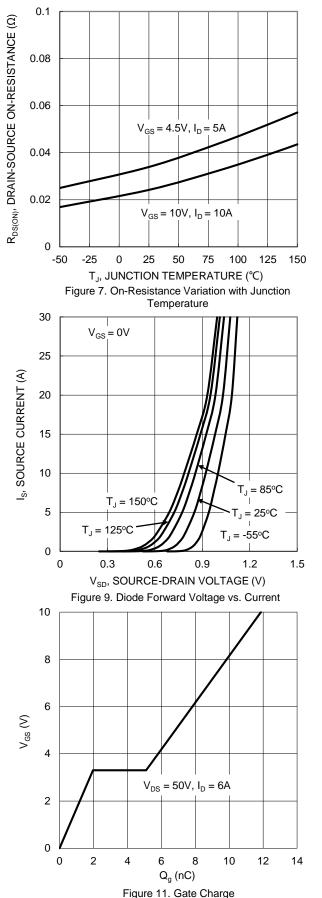


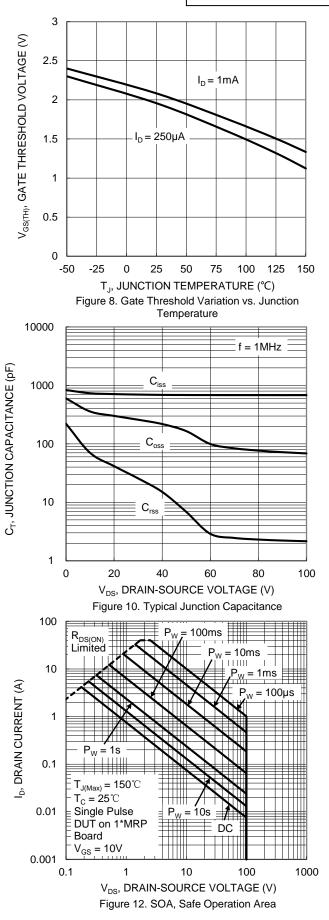


DMT10H032LDV Document number: DS42043 Rev. 3 - 2



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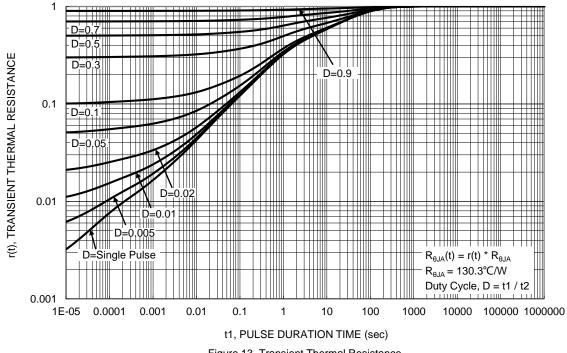
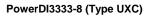


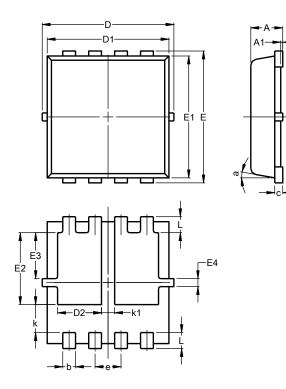
Figure 13. Transient Thermal Resistance



## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.



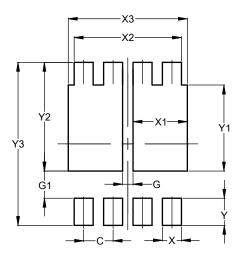


PowerDI3333-8 (Type UXC)					
Dim	Тур				
A	Min 0.75	<b>Max</b> 0.85	0.80		
A1	0.00	0.05			
b	0.25	0.40	0.32		
C	0.10	0.25	0.15		
D	3.20	3.40	3.30		
D1	2.95	3.15	3.05		
D2	0.90	1.30	1.10		
E	3.20	3.40	3.30		
E1	2.95	3.15	3.05		
E2	1.60	2.00	1.80		
E3	0.95	1.35	1.15		
E4	0.10	0.30	0.20		
е	_	-	0.65		
L	0.30	0.50	0.40		
k	0.50	0.90	0.70		
<b>k</b> 1	0.13	0.53	0.33		
а	0°	12°	10°		
All Dimensions in mm					

## Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

### PowerDI3333-8 (Type UXC)



Dimensions	Value (in mm)		
С	0.650		
G	0.230		
G1	0.600		
Х	0.420		
X1	1.200		
X2	2.370		
X3	2.630		
Y	0.600		
Y1	1.900		
Y2	2.400		
Y3	3.600		



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